



FMMT495

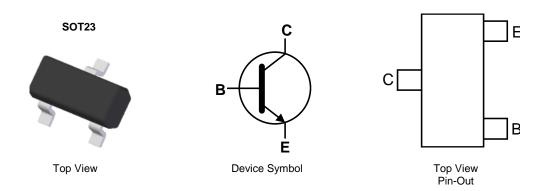
150V NPN SILICON PLANAR MEDIUM POWER TRANSISTOR IN SOT23

Feature

- BV_{CEO} > 150V
- I_C = 1A Continuous Collector Current
- I_{CM} = 2A Peak Pulse Current
- 500mW Power Dissipation
- h_{FE} Characterised up to 1A for High Current Gain Hold Up
- Totally Lead-Free & Fully RoHS compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- Qualified to AEC-Q101 Standards for High Reliability
- PPAP capable (Note 4)

Mechanical Data

- Case: SOT23
- Case Material: Molded Plastic, "Green" Molding Compound.
 UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish Matte Tin Plated Leads, Solderable per MIL-STD-202, Method 208 (3)
- Weight 0.008 grams (Approximate)



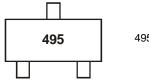
Ordering Information (Notes 4 & 5)

Part Number	Compliance	Marking	Reel Size (inches)	Tape Width (mm)	Quantity per Reel
FMMT495TA	AEC-Q101	495	7	8	3,000
FMMT495TC	AEC-Q101	495	13	8	10,000
FMMT495QTA	Automotive	495	7	8	3,000

Notes:

- 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant.
- See http://www.diodes.com/quality/lead_free.html for more information about Diodes Incorporated's definitions of Halogen and Antimony free, "Green" and Lead-Free.
- 3. Halogen and Antimony free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
- 4. Automotive products are AEC-Q101 qualified and are PPAP capable. Automotive, AEC-Q101 and standard products are electrically and thermally the same, except where specified. For more information, please refer to http://www.diodes.com/quality/product_compliance_definitions/.
- 5. For packaging details, go to our website at http://www.diodes.com/products/packages.html.

Marking Information



495 = Product Type Marking Code



Maximum Ratings (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Collector-Base Voltage	V_{CBO}	170	V
Collector-Emitter Voltage	$V_{\sf CEO}$	150	٧
Emitter-Base Voltage	V_{EBO}	7	V
Continuous Collector Current	Ic	1	Α
Peak Pulse Current	I _{CM}	2	Α
Base Current	I _B	200	mA

Thermal Characteristics (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Power Dissipation (Note 6)	P_{D}	500	mW
Thermal Resistance, Junction to Ambient (Note 6)	$R_{ heta JA}$	250	°C/W
Thermal Resistance, Junction to Lead (Note 7)	$R_{ heta JL}$	197	°C/W
Operating and Storage Temperature Range	$T_{J_i}T_{STG}$	-55 to +150	°C

ESD Ratings (Note 8)

Characteristic	Symbol	Value	Unit	JEDEC Class
Electrostatic Discharge – Human Body Model	ESD HBM	4,000	V	3A
Electrostatic Discharge – Machine Model	ESD MM	≥ 400	V	С

Notes:

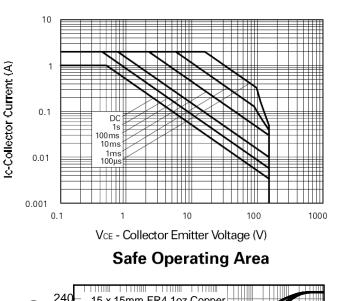
^{6.} For a device surface mounted on 15mm x 15mm FR4 PCB with high coverage of single sided 1 oz copper, in still air conditions; the device is measured when operating in a steady-state condition.

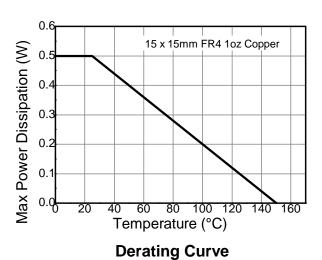
^{7.} Thermal resistance from junction to solder-point (at the end of the collector lead).

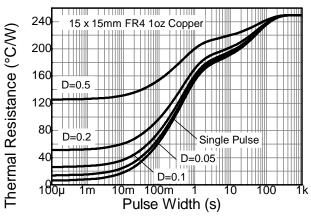
8. Refer to JEDEC specification JESD22-A114 and JESD22-A115.

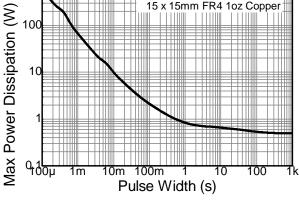


Thermal Characteristics and Derating Information









Transient Thermal Impedance

Pulse Power Dissipation



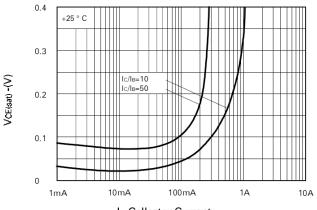
Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition
Collector-Base Breakdown Voltage	BV _{CBO}	170	_	_	V	$I_{C} = 100 \mu A$
Collector-Emitter Breakdown Voltage (Note 9)	BV _{CEO}	150	_	_	V	$I_C = 10mA$
Emitter-Base Breakdown Voltage	BV _{EBO}	7	_	_	V	$I_{E} = 100 \mu A$
Collector Cutoff Current	I _{CBO}	_	_	100	nA	V _{CB} = 150V
Emitter Cutoff Current	I _{EBO}	_	_	100	nA	$V_{EB} = 5V$
Collector Emitter Cutoff Current	I _{CES}	_	_	100	nA	V _{CE} = 150V
	h _{FE}	100	_	_	_	$I_C = 1mA$, $V_{CE} = 10V$
Static Forward Current Transfer Ratio (Note 9)		100	_	300		$I_C = 250 \text{mA}, V_{CE} = 10 \text{V}$
Static Forward Current Transfer Ratio (Note 9)		50	_	_		$I_C = 500mA$, $V_{CE} = 10V$
		10	_	_		$I_C = 1A, V_{CE} = 10V$
Collector-Emitter Saturation Voltage (Note 9)	Vce(sat)	_	_	0.2	V	$I_C = 250 \text{mA}, I_B = 25 \text{mA}$
Collector-Entitler Saturation Voltage (Note 9)		_	_	0.3	V	$I_C = 500 \text{mA}, I_B = 50 \text{mA}$
Base-Emitter Turn-On Voltage (Note 9)	V _{BE(ON)}	_	_	1.0	V	$I_C = 500 \text{mA}, V_{CE} = 10 \text{V}$
Base-Emitter Saturation Voltage (Note 9)	V _{BE(SAT)}	_	_	1.0	V	$I_C = 500 \text{mA}, I_B = 50 \text{mA}$
Output Capacitance	Сово	_	_	10	pF	V _{CB} = 10V, f = 1MHz
Transition Frequency	f⊤	100	_	_	MHz	$V_{CE} = 10V, I_{C} = 50mA,$ f = 100MHz

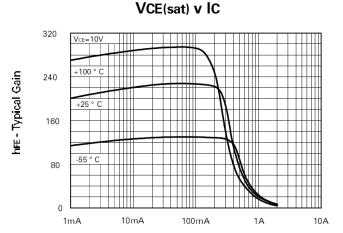
Notes: 9. Measured under pulsed conditions. Pulse width \leq 300 μ s. Duty cycle \leq 2%.



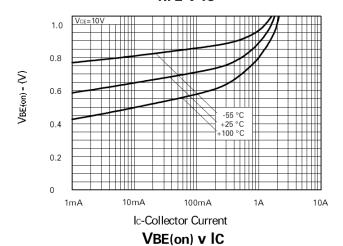
Typical Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

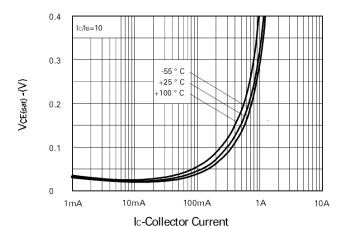




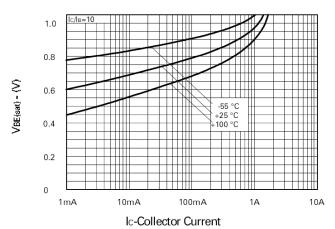


Ic-Collector Current **hFE V IC**





VCE(sat) v IC



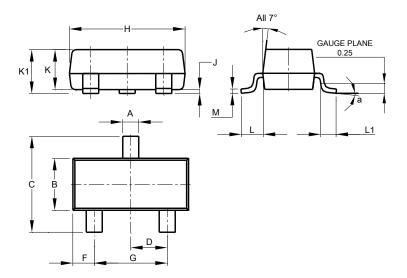
VBE(sat) v IC



Package Outline Dimensions

Please see AP02001 at http://www.diodes.com/_files/datasheets/ap02001.pdf for the latest version.

SOT23

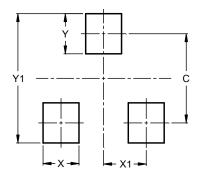


SOT23					
Dim	Min	Max	Тур		
Α	0.37	0.51	0.40		
В	1.20	1.40	1.30		
С	2.30	2.50	2.40		
D	0.89	1.03	0.915		
F	0.45	0.60	0.535		
G	1.78	2.05	1.83		
H	2.80	3.00	2.90		
7	0.013	0.10	0.05		
K	0.890	1.00	0.975		
K1	0.903	1.10	1.025		
L	0.45	0.61	0.55		
L1	0.25	0.55	0.40		
М	0.085	0.150	0.110		
а	0°	8°			
All Dimensions in mm					

Suggested Pad Layout

Please see AP02001 at http://www.diodes.com/_files/datasheets/ap02001.pdf for the latest version.

SOT23



Dimensions	Value (in mm)		
С	2.0		
Х	0.8		
X1	1.35		
Y	0.9		
Y1	2.9		



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